



A high-brightness, accelerator-based EUV source for actinic mask inspection

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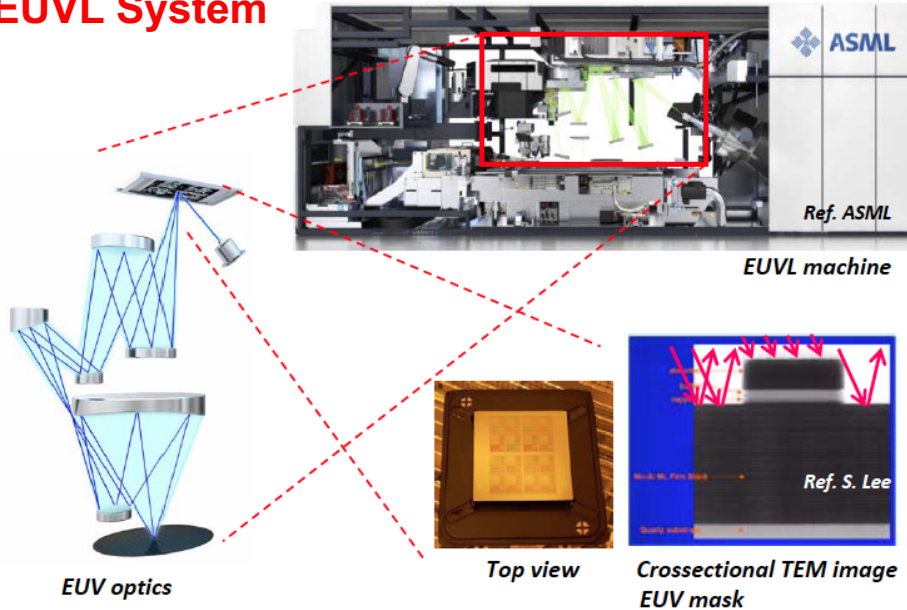
- **Background & Motivation**
 - EUV mask inspection
 - Actinic patterned mask inspection using lensless imaging
 - Source requirements
- **COSAMI: Accelerator-based high-brightness EUV source**
 - Optics design
 - Technical sub-systems
 - Undulator
 - Vacuum system
 - Injector linac
 - Radio-frequency system
 - Radiation shielding
- **Conclusions**

Not discussed

- *Magnets*
- *Non-critical subsystems (diagnostics, controls, power supplies)*
- *Injection to storage ring*

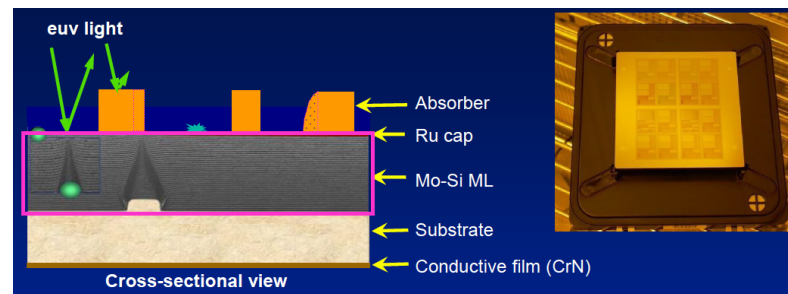
EUV Mask inspection

EUVL System



Mask inspection:

- Masks are Mo/Si multilayer
- Mask inspection is a big challenge:
 - Mask blank inspection
 - Patterned mask inspection
 - Mask review



Actinic mask metrology for EUVL is missing

EUV Infrastructure Readiness Snapshot

Judged as of Today

EUV infrastructure has 8 key programs

3 are ready or near-ready now, 4 are in development, 1 has significant gaps



E-beam Mask Inspection: In use for low volume production. Need TPT increase.



Actinic Blank Inspection (ABI): Ready for qualification of HVM quality blanks



AIMS Mask Inspection: Imaging demonstrated; systems shipping to field



Pellicle: ASML commercializing – needs acceleration; production phase in 2H'17 – cannot slip schedule



EUV blank quality: Process and yield improvements continue



Blank multi-layer deposition tool: Improving defect results. Multiple deposition techniques being evaluated to define HVM tool approach.



EUV resist QC: RMQC center at IMEC expected online in 2017



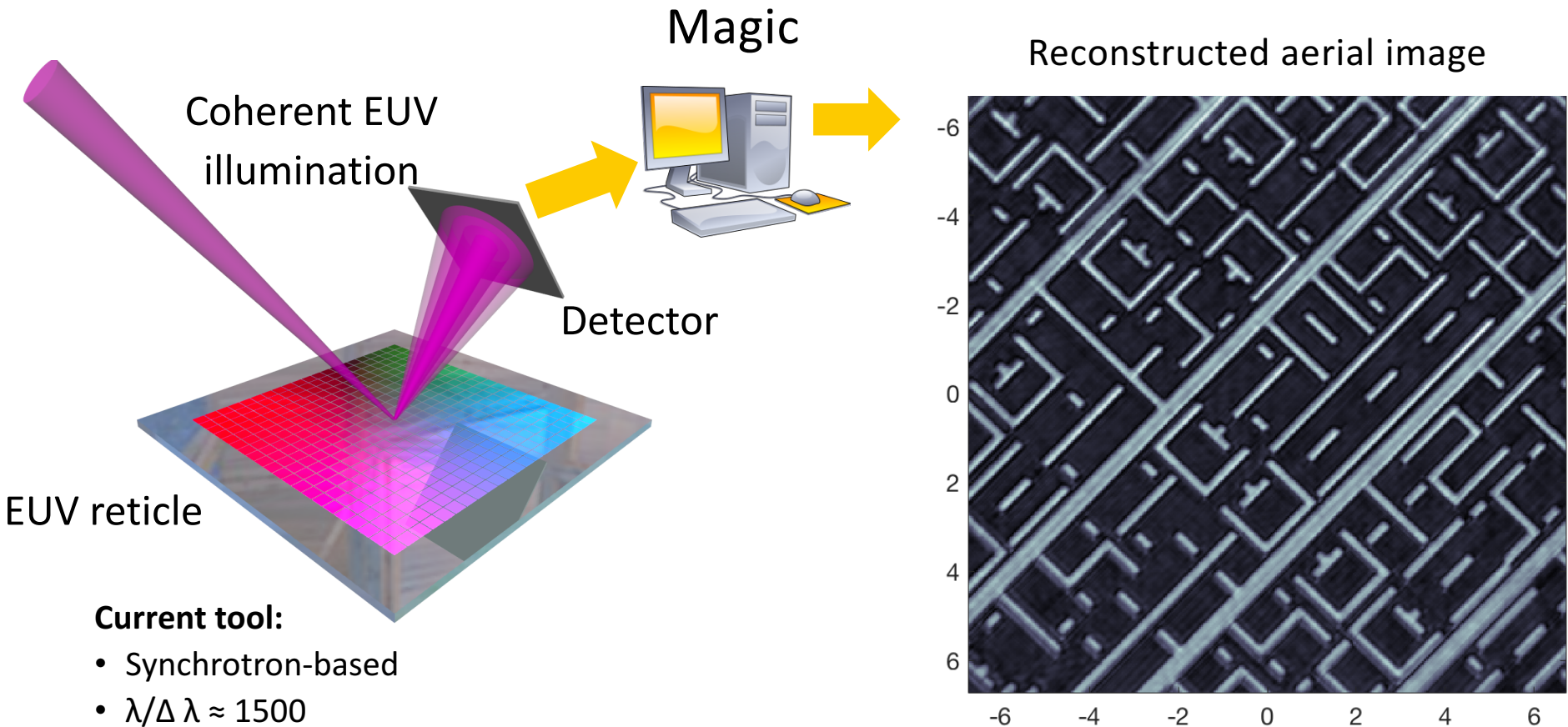
Actinic Patterned Mask Inspection (APMI): High resolution PWI for fab. Still need actinic inspection in mask shop.

SPIE BACUS MEETING, Monterey, September 2017

Panel Discussion: How to survive the first and even second node of EUV without actinic mask inspection?

**EUV Source is the major challenge: Limited brightness (not flux)
and stability and availability**

Actinic pattern inspection platform based on Coherent Diffraction Imaging (CDI)



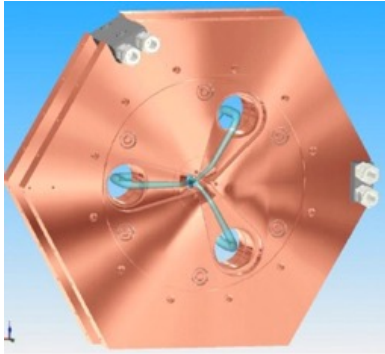
Current tool:

- Synchrotron-based
- $\lambda/\Delta\lambda \approx 1500$
- Max sample size: $2 \times 2 \text{ cm}^2$
- Inspection area: $200 \times 200 \text{ }\mu\text{m}^2$
- $\text{Na}_{\text{max}}: 0.24$
- Resolution limit: 34 nm

This method requires much higher brightness than other imaging or inspection methods!!

EUV source for metrology

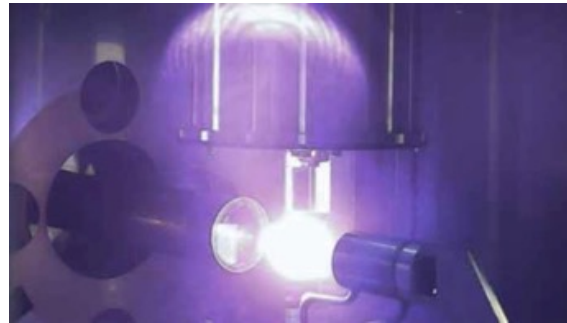
Z-pinch



- Off-the-shelf
- High availability
- Maintenance
- Debris
- Sufficient flux
- Low-brightness

10 W/mm².sr

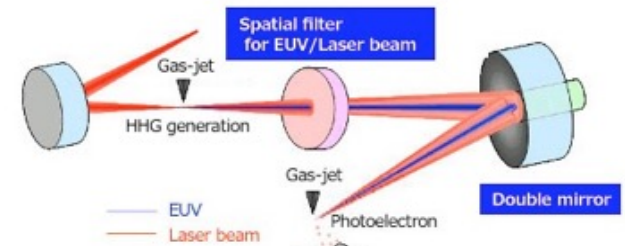
LPP/DPP



- Low availability
- Low stability
- Debris
- Maintenance
- High flux
- Relatively high brightness

100 W/mm².sr

HHG



- Low availability
- Low stability
- High brightness
- Low flux

1 μW

Compact sources

Helios

processing (chip-
the billion-dollar
of Instruments are
here considerable
equipment makers
synchrotron, high vac-
uum technology, synchrotron,
ography, the prod-
uct circuit patterns
in silicon wafers, is
at edge of profound

resetting US and
microchip com-
panies believe that optical
y will serve for
red memory chips
rapidly. X-ray litho-
graphy explored for
ing generation of
t chips, a memory
water than that of
optics. In order
cuits, dimensions
run are required
h of a human hair.



1 Instruments' core

Oxford Instruments has developed
miniaturized synchrotron which is
source of high intensity X-rays. Hel
is simply a lamp, a particularly brillia
X-ray light source for lithography whi
fits like a machine tool into a semicon-
ductor fabrication plant, serving
score of processing lines and design
to operate round the clock in an ex-
ceptionally reliable way.

The synchrotron has become the fl-
ship of the semiconductor division
portfolio. The first Helios was order
by IBM for its 31 billion Advanced
Semiconductor Technology Centre
East Fishkill, NY.

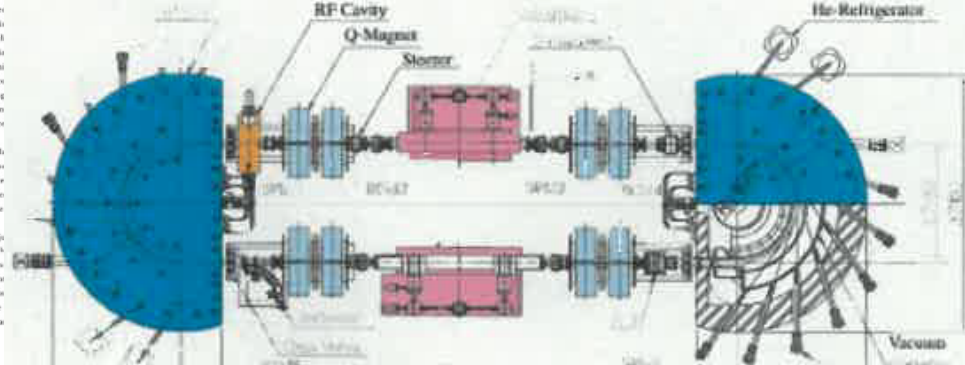
A new source of light, however, is
the beginning of advances in X-ray litho-
graphy demand comparable progress
associated areas. Oxford Instrum-
ent-beam technology fits perfectly in
precision mask repair system, able
manipulate the lithography membra

Helios, a superconducting magnetron used track
to produce a beam of X-rays suitable for lithograph
semiconductor memory chips

NEW JERSEY CONCORD MASSACHUSETTS 019

technologies as well as diversification

Aurora



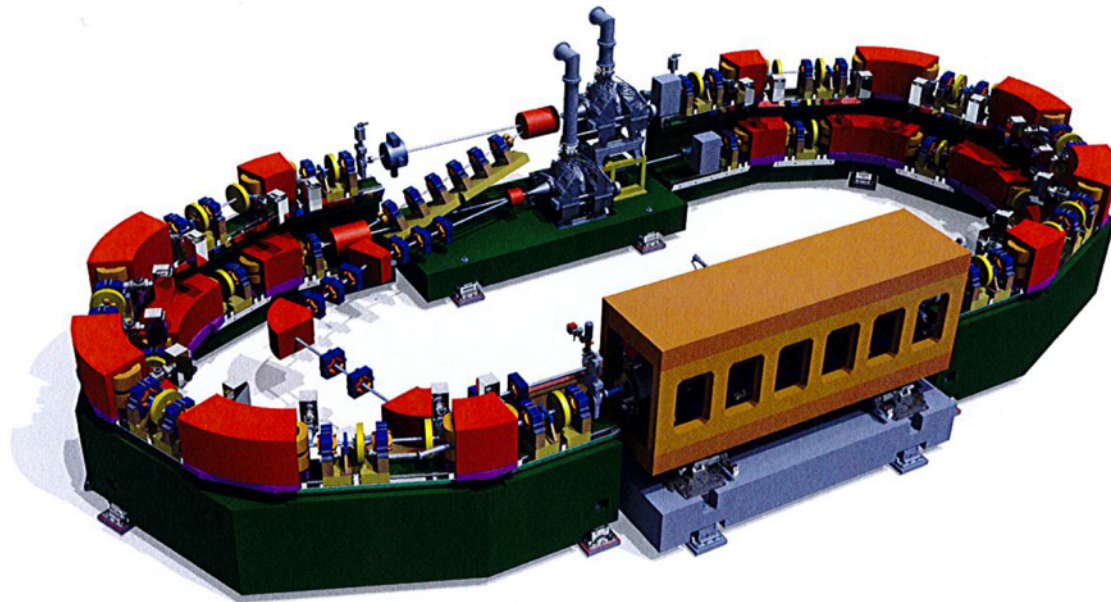
Well established technology:

- Many tools are developed in 80s and 90s
- Designed for HVM but could not achieve the moving target of power requirements

Motivation for this study

- A source for EUV metrology:
 - Sufficient Flux to perform mask inspection within 7 hours, i.e. 100 mW
 - High coherence for CDI
 - Intensity stability (0.1%)
 - Compactness:
 - As compact as possible
 - But without increasing the machine complexity
 - Really compact
 - Minimal down time: Scheduled (<5%) and unscheduled (<1%)
 - Reliability: use proven technology and robust design
 - Cost& Development Time

Compact EUV Metrology Source „COSAMI“

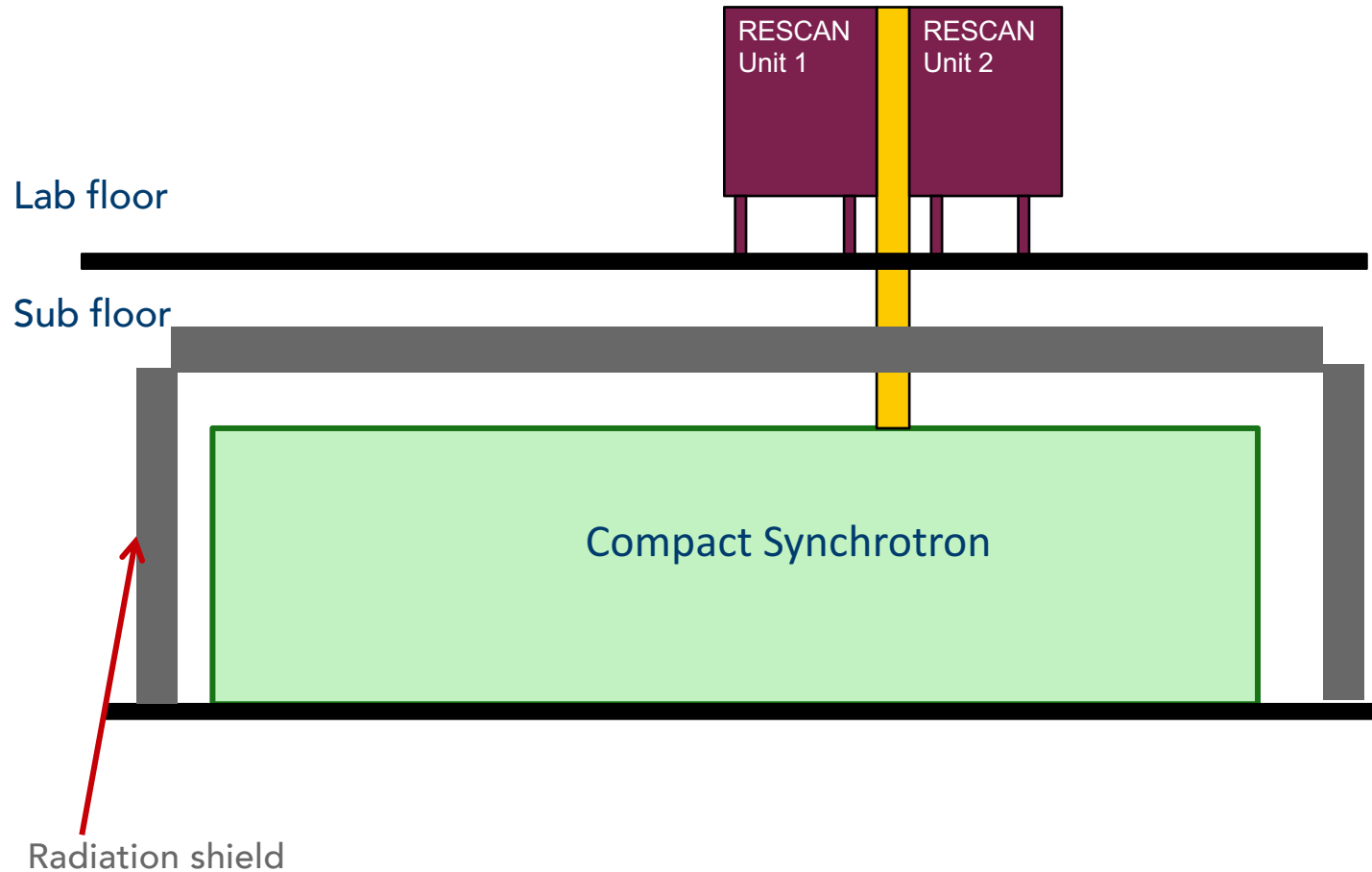


Wavelength	13.5 nm
Flux	~100 mW
Brilliance	~ 10^9 W/(mm ² · strd)
Beam energy/beam current	430 MeV/150 mA
Pulse structure	~50 ps every 2 ns
Injection system	Top-up mode
Beam stability	0.1%
Availability	>95%
Reliability	<1% down time
Footprint	5m × 12m

Innovative solutions

- adapt technology of Diffraction Limited Storage Rings
- Co-centric design: vertical stacking of booster and ring → small footprint
- multi-bend magnet lattice
- implementation of undulator
- combined function magnets
- small vacuum chambers with NEG coating
- Photo injector

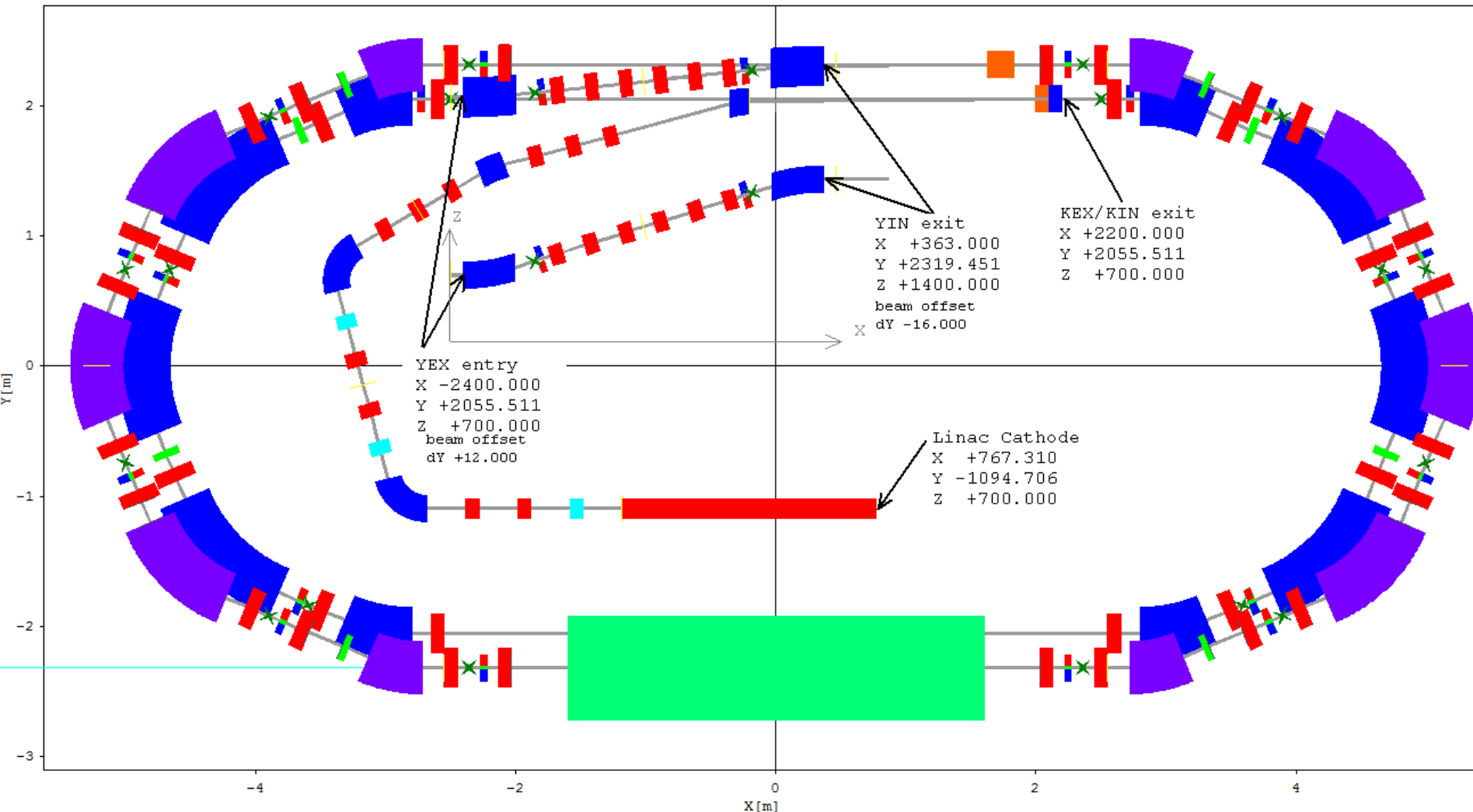
Does it fit into a fab?

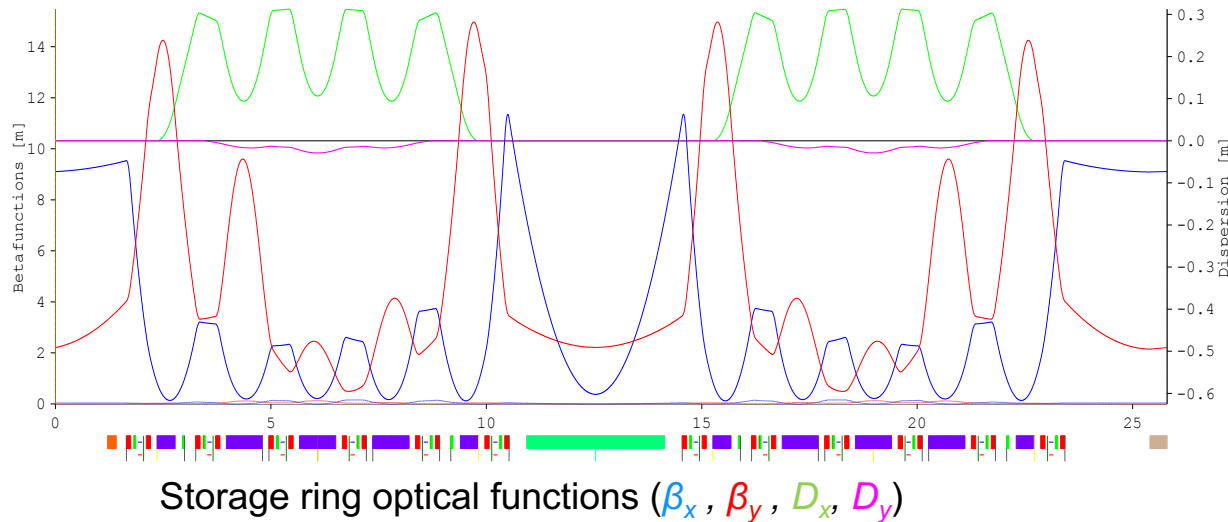


Facility layout

Race-track geometry: Two 5-bend achromat arcs and two straights. One straight for the undulator and one for injection and RF.

- Ring: 430 MeV, 25.8 m
- Booster: 43 → 430 MeV, 24.0 m
- BR transfer line –18.6° inclination
- LB transfer line
- Gun/Linac: 43 MeV, 2.1 m





Lattice design

- Strong horizontal focussing: strong quads \rightarrow small magnet bore; strong sextupoles to correct chromaticity.
- Weak dispersion (MBA) ensures adequate momentum acceptance despite small aperture \rightarrow needed to reduce particle loss to Touscheck scattering.
- Skew-quad windings in sextupole to generate some vertical emittance \rightarrow reduce Touscheck scattering.
- Small β_x at center of undulator \rightarrow minimise source-point size \rightarrow brightness.
- β_y reduced at undulator extremities to reduce particle losses (small vertical gap).
- Magnetic elements would be installed / aligned on girders. Simulations show orbit correction due to misalignments (100 μm , 100 μrad) easily corrected with 1 mrad correction coils.

Nominal storage ring parameters

Circumference [m]	25.8	Energy [MeV]	430
Working Point $Q_{x/y}$	4.73 / 1.58	Radiation loss/turn [keV]	2.83
Natural chromaticity $\xi_{x/y}$	-9.7 / -6.9	Emittance [nm]	5.50
Momentum compaction α_c	0.0258	Relative energy spread	$4.13 \cdot 10^{-4}$
Hor. damping partition J_x	1.54	Damping times $\tau_{x/y/E}$ [ms]	16.6 / 25.6 / 17.5

Machine length corresponds to 43 RF wavelengths. 24 “buckets” are filled to leave a gap in the bunch train to combat trapped ions. Total charge in ring is ~ 17 nC (assuming $I = 200$ mA, to have some margin).

Non-linear beam dynamics studies investigated to evaluate:

Dynamic aperture ✓ greater than physical aperture

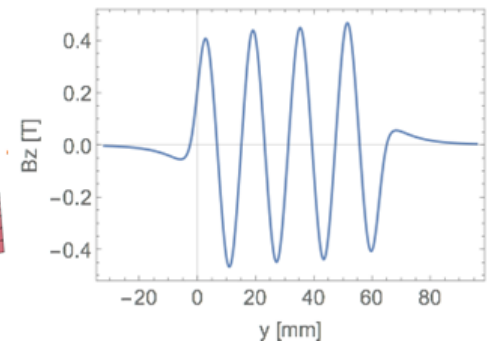
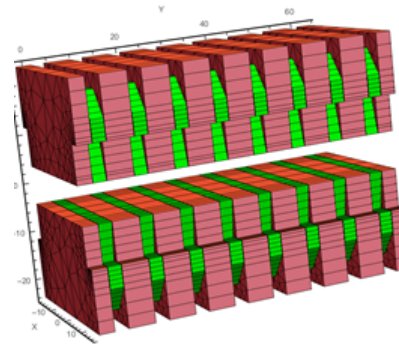
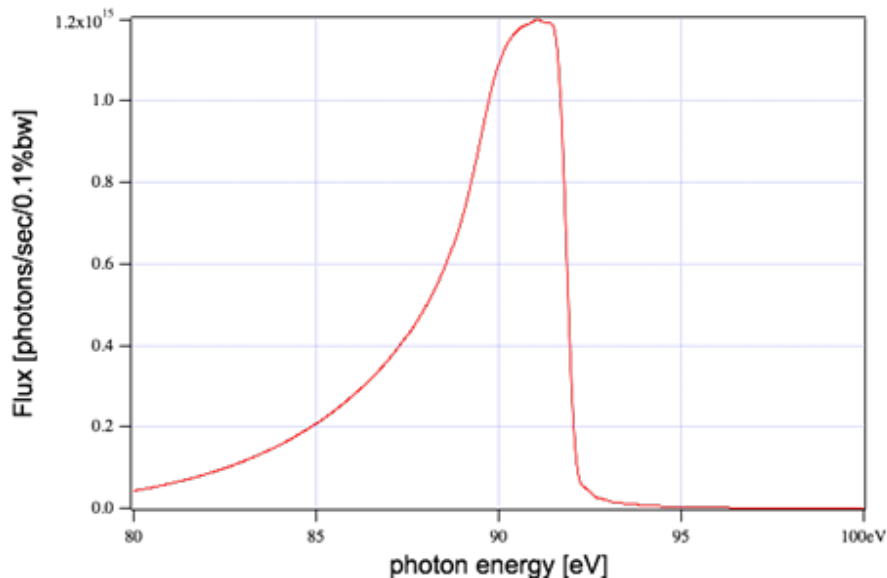
Touscheck scattering \rightarrow 400 kV RF voltage needed to optimise life-time

Intra-beam scattering \rightarrow some emittance dilution.

Life-times of ~ 15 minutes calculated \rightarrow Top-up frequency > 1 Hz to maintain 0.1% intensity stability.

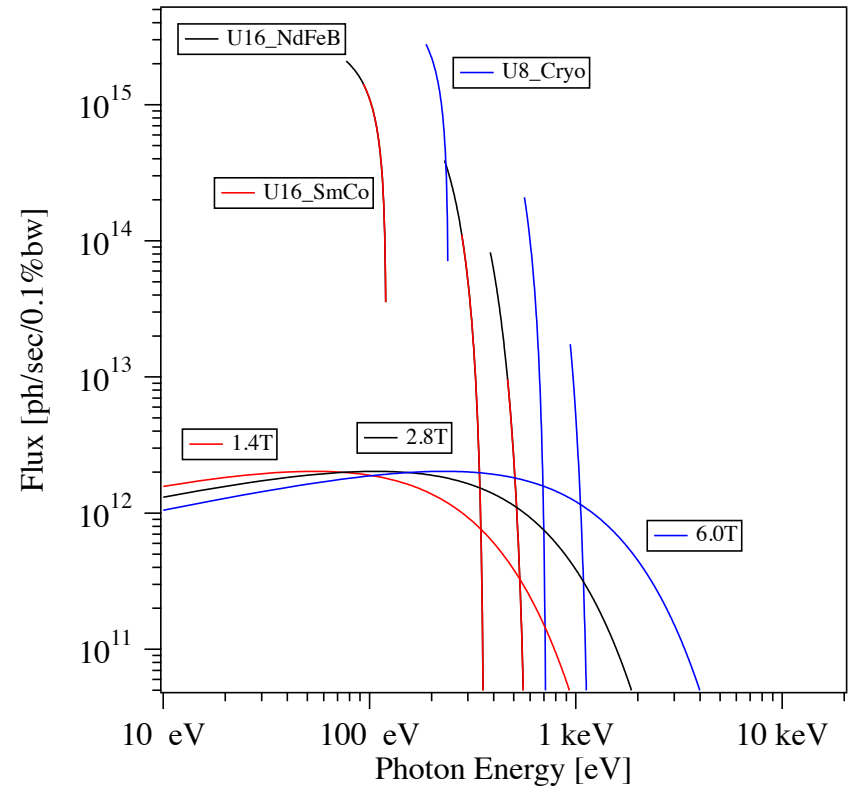
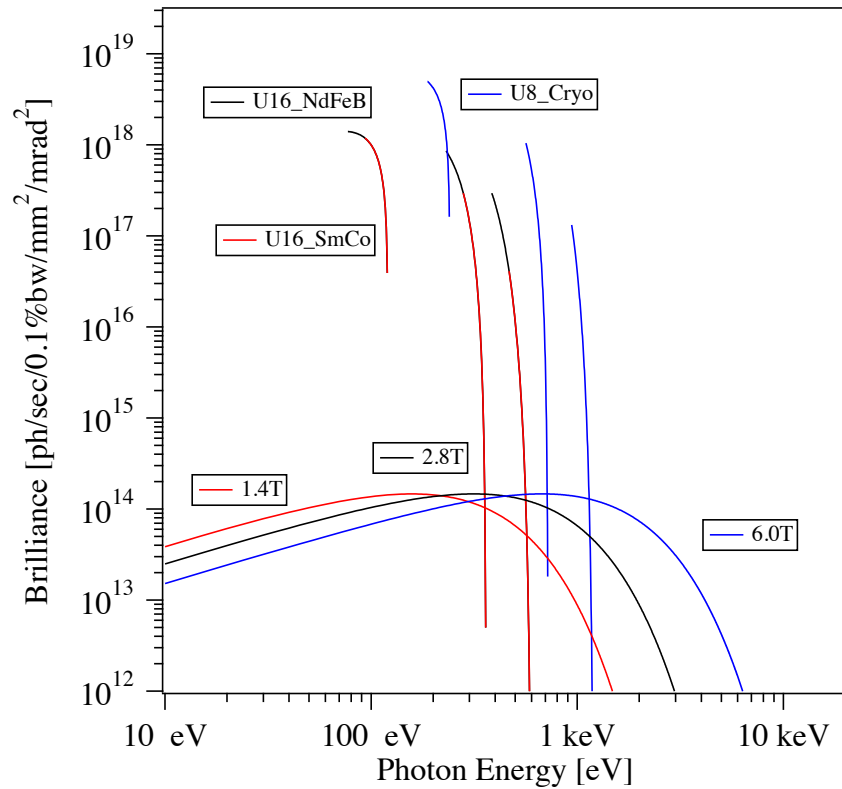
The Undulator

- Design based on undulator assemblies for SLS and SwissFEL.
 - Field on axis = 0.42 T, $\lambda_u = 16$ mm, gap = 7 mm (fixed in operation).
 - Good field region = ± 12 mm
 - Magnetic material: NdFeB with diffused Dy \rightarrow good combination of B_r and H_c
 \rightarrow less sensitive to demagnetisation due to beam loss (i.e. radiation hard).
- Produces flux / brightness required for mask inspection at 13.5 nm (92 eV).
 - Flux = 1.2×10^{15} ph/s/0.1% BW
 - Brilliance = 6×10^{17} ph/s/mm²/mrad²/0.1% BW



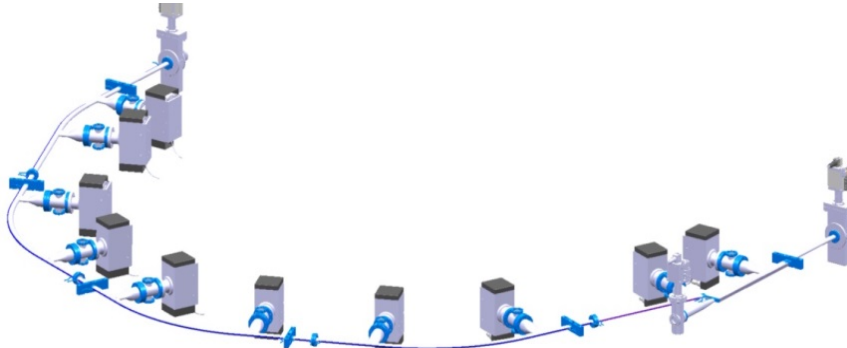
Simulation of 4 periods

EUV source brightness curves – 430 MeV comparison with other undulator / dipole magnets

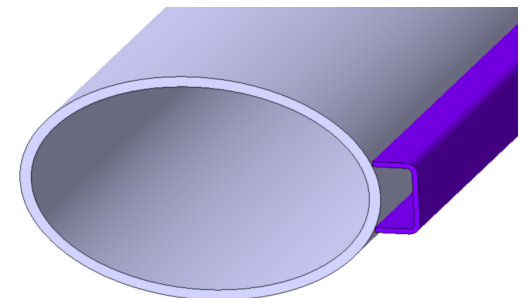
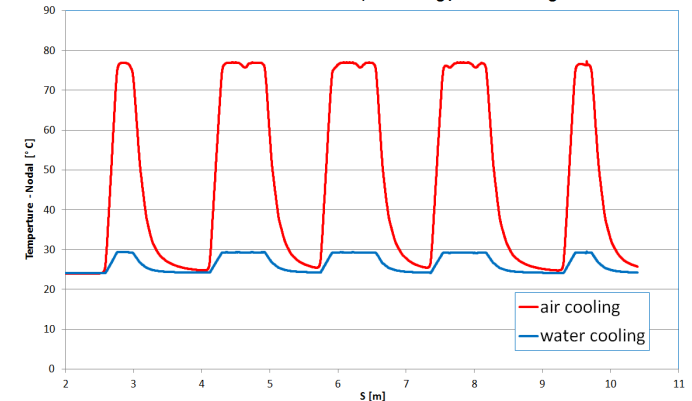


- Vacuum system must provide sufficiently low base pressure ($< 10^{-9}$ mbar) to due to scattering from residual gas.
 - Elliptical vacuum chamber of 30 mm (H) x 20 mm (V) adopted.
 - “small” chamber to allow strong magnet gradients.
- Base pressure dominated by photo-desorption due to synchrotron radiation.
- Low energy ring \rightarrow low heat load ~ 85 W/m but temperature rise is still significant
 - Forced cooling needed

\rightarrow full NEG coating of chamber required

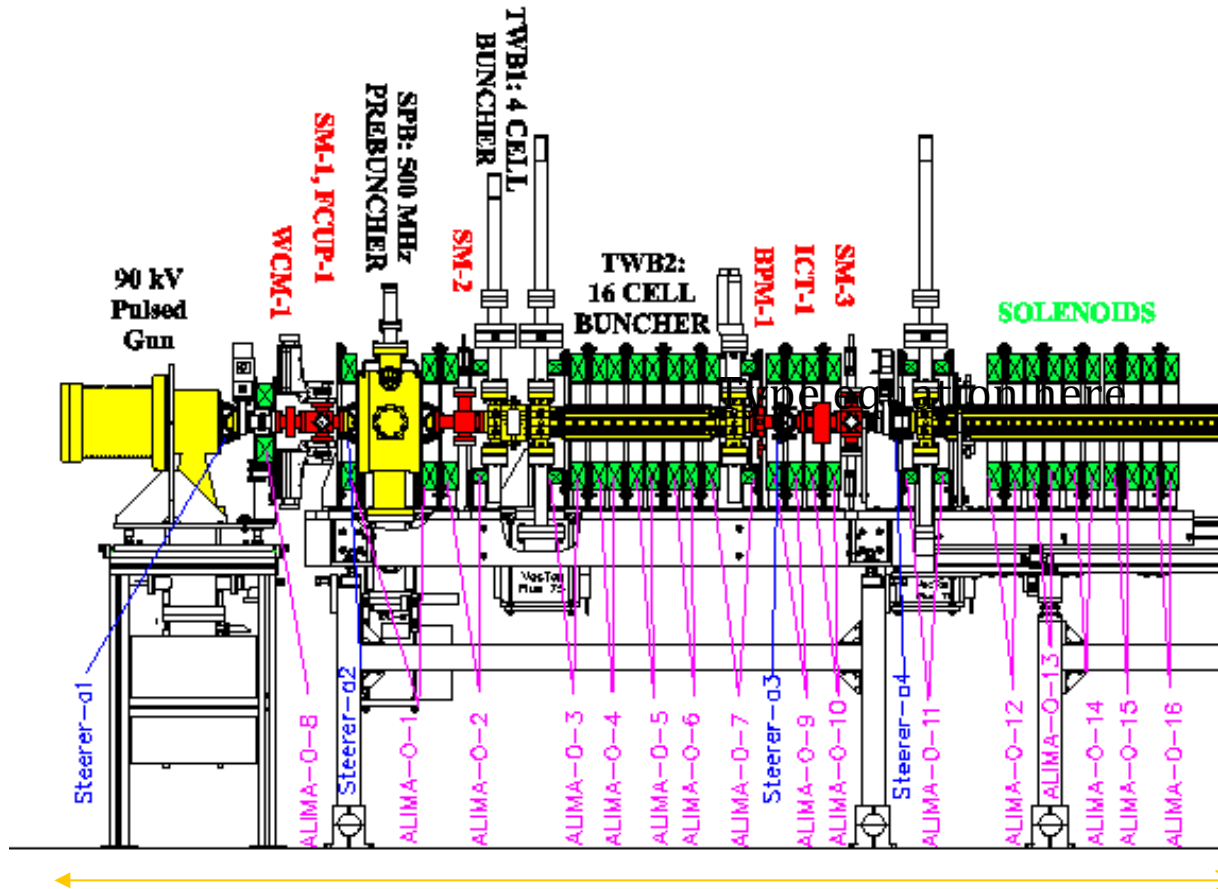


Temperature distribution along circumference of vacuum chamber
stainless steel tube 30 x 20 mm, air cooling / water cooling



Cooling channel 3mm x 6mm

Standard Injector Linac: available commercially

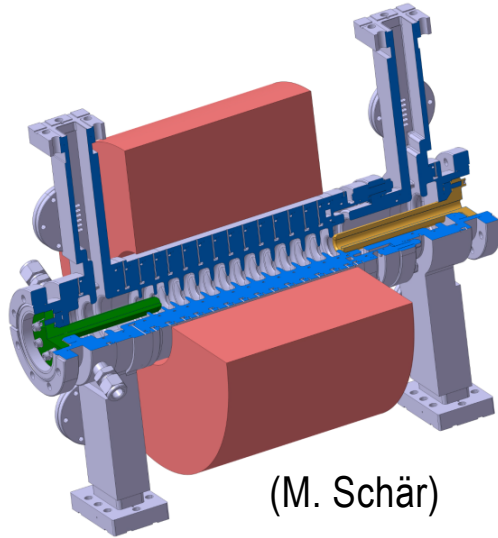


- Proven technology
- Can be fed by 1 S-band Klystron
- Needs space for HV-area and bunching!
- Needs complex waveguide system
- Some jitter in energy and charge
- Needs about 5x5m² floor space for Klystron and magnet power supplies

Ca. 4m for bunching and acceleration to 20MeV

Takes up too much space !

The EUV source would use a Photo-Injector linac



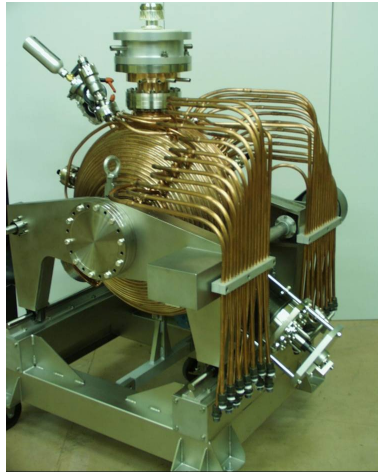
(M. Schär)



- Combine the high brightness **travelling wave gun** with **SwissFEL 2m C-band structure**:
Relaxed gradient, laser profile and repetition rate,
Increases number of cells to reach the energy,
simplify the couplers and focusing magnet.
- Advantages: Compact and simple design
- Needs UV-Laser system
- Synchronization more complex !
With $f_b = 71.4\text{MHz}$: $5.712\text{GHz} = 80f_b$
 $499.8\text{MHz} = 7f_b$
- Timing for bucket allocation in storage ring more complex (but can still be achieved).

SR Radio-Frequency system

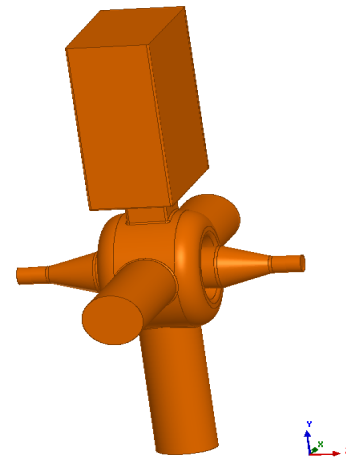
Identification of hardware requirements – use existing commercial solutions



ELETTRA 500 MHz cavity



65 kW solid state amp.



ALS 3rd harmonic cavity

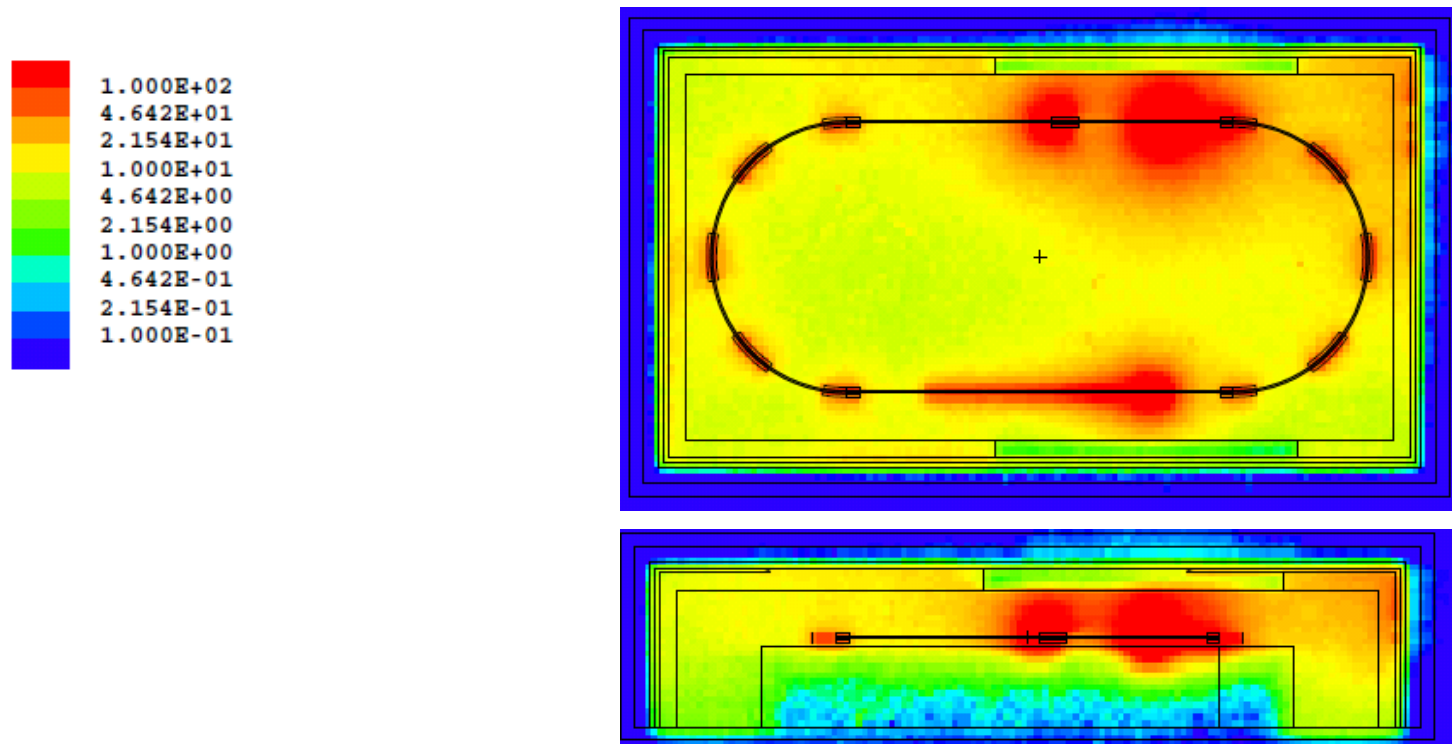
RF cavity, power source, waveguide, phase/amplitude regulation

Studies of instability thresholds → shows advantage of 3rd Harmonic Cavity (3HC)

Microwave instability driven by ring impedance; CBI driven by longitudinal or transverse Higher Order Modes of the RF cavity.

Radiation shielding

- Performed using codes MCNPX 2.7.0 (local) / MCNP 6.1 (outer wall)
Loss rates $\sim 1.2 \times 10^8$ electrons/s at 430 MeV \rightarrow ICRP data used to convert flux to dose rates. Losses dominated by storage ring.



Ensuring the radiation safety is straightforward.

- COSAMI is a viable solution to the EUV metrology in general
- We did conceptual design and studied the sub-systems
- Optimization undulator vs. storage ring
 - Conceptual design
 - Lattice design
 - layout & performance ✓
 - non-linear dynamics ✓
 - beam lifetime ✓
 - ion trapping ✓
 - injection to storage ring (WIP)
 - Undulator ✓
 - DC-Magnets ✓
 - Pulsed magnets (WIP)
 - RF-systems ✓
 - Vacuum system ✓
 - Radiation shielding ✓ Local shielding (WIP)
 - Non-critical subsystems: diagnostics, controls, power supplies

Acknowledgements

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Advanced Accelerator Technologies contributed to 3-D integration drawings

Thanks for your attention.